

A 0.01 mm²10MHz RC Frequency Reference with a 1-Point On-Chip-Trimmed Inaccuracy of $\pm 0.28\%$ from -45°C to 125°C in 0.18 μm CMOS

An, Xiaomeng; Pan, Sining; Jiang, Hui; Makinwa, Kofi A.A.

DOI

[10.1109/ISSCC42615.2023.10067530](https://doi.org/10.1109/ISSCC42615.2023.10067530)

Publication date

2023

Document Version

Final published version

Published in

2023 IEEE International Solid-State Circuits Conference, ISSCC 2023

Citation (APA)

An, X., Pan, S., Jiang, H., & Makinwa, K. A. A. (2023). A 0.01 mm²10MHz RC Frequency Reference with a 1-Point On-Chip-Trimmed Inaccuracy of $\pm 0.28\%$ from -45°C to 125°C in 0.18 μm CMOS. In *2023 IEEE International Solid-State Circuits Conference, ISSCC 2023* (pp. 60-62). (Digest of Technical Papers - IEEE International Solid-State Circuits Conference; Vol. 2023-February). Institute of Electrical and Electronics Engineers (IEEE). <https://doi.org/10.1109/ISSCC42615.2023.10067530>

Important note

To cite this publication, please use the final published version (if applicable). Please check the document version above.

Copyright

Other than for strictly personal use, it is not permitted to download, forward or distribute the text or part of it, without the consent of the author(s) and/or copyright holder(s), unless the work is under an open content license such as Creative Commons.

Takedown policy

Please contact us and provide details if you believe this document breaches copyrights. We will remove access to the work immediately and investigate your claim.

Green Open Access added to TU Delft Institutional Repository

'You share, we take care!' - Taverne project

<https://www.openaccess.nl/en/you-share-we-take-care>

Otherwise as indicated in the copyright section: the publisher is the copyright holder of this work and the author uses the Dutch legislation to make this work public.

3.4 A 0.01mm² 10MHz RC Frequency Reference with a 1-Point On-Chip-Trimmed Inaccuracy of ±0.28% from -45°C to 125°C in 0.18µm CMOS

Xiaomeng An^{*1,2}, Sining Pan^{*1,3}, Hui Jiang², Kofi A. A. Makinwa¹

¹Delft University of Technology, Delft, The Netherlands

²Silicon Integrated, Eindhoven, The Netherlands, ³Tsinghua University, Beijing, China

*Equally-Credited Authors (ECAs)

CMOS frequency references based on RC oscillators are usually preferred over bulky crystals in IoT applications [1-5]. However, due to the process spread and finite temperature coefficient (TC) of most on-chip resistors, RC oscillators require trimming and temperature compensation to achieve decent accuracy. Enabled by high-resolution trimming techniques such as $\Delta\Sigma$ [1,2] or pulse-density [3] modulation, recent designs can obtain good accuracy (<0.1%) at the expense of large chip area. However, existing compact (<0.02mm²) designs suffer from frequency errors in the order of 1% or more [4,5]. Moreover, their temperature compensation schemes usually require the use of resistors with complementary TCs, which are not available in all CMOS technologies.

This paper describes a compact RC frequency reference with on-chip circuits with which both its TC and absolute frequency f_0 can be trimmed. Fabricated in a standard 0.18µm technology, the 0.01mm² 10MHz reference achieves a ±0.28% inaccuracy from -45°C to 125°C after 1-point trim, which represents the state-of-the-art for designs with a similar area. Moreover, the proposed temperature compensation scheme does not require resistors with complementary TCs, which significantly extends its application scope.

Figure 3.4.1 (top-left) shows the block diagram of the proposed RC-based frequency reference, which is based on a frequency-locked-loop (FLL) [3]. Driven by the output frequency F_{OUT} of a voltage-controlled oscillator (VCO), an RC network outputs a frequency-dependent voltage (V_C), which is compared with a reference voltage (V_R) derived from a resistive divider, integrated and then used to drive the VCO. Due to the large DC loop gain, the steady-state difference between V_R and V_C will be near zero, resulting in an output frequency that only depends on the properties of the RC network and the resistive divider.

On-chip resistors typically have large TCs, up to 1000ppm/°C, while that of on-chip MIM caps (~30ppm/°C) is relatively negligible. As a result, the TC compensation of RC oscillators is often achieved by combining resistors with complementary TCs to realize a so-called “zero-TC” composite resistor R_0 , which ensures that V_C is temperature independent [3]. However, this requires a high-resolution resistor-trimming network, which introduces (trim-code dependent) parasitic capacitances that increase the inaccuracy of f_0 . Furthermore, not all CMOS technologies have a suitable combination of resistors.

In this work, R_0 is realized as a single resistor, and TC compensation is achieved by designing the TC of the reference voltage V_R to match that of V_C . In the chosen 0.18µm CMOS technology, both R_0 and R_1 are implemented as p-poly resistors (-0.02%/°C), while R_2 is implemented by a trimmable combination of p-poly and n-poly (-0.15%/°C) resistors. As shown in Fig. 3.4.1 (bottom-left), by tuning the width of the two types of resistors so that they (nominally) have the same resistance per unit length, the length of R_2 , and thus its resistance, will be trim-code independent, allowing f_0 to be trimmed in an orthogonal manner. In this work, the TC of the frequency reference can be trimmed from -40ppm/°C to 40ppm/°C in 16 steps. As shown in Fig. 3.4.1 (bottom-right), the nominal frequency f_0 is trimmed with the help of a coarse-fine capacitive DAC. This results in a trimming range of ±30%, with a worst-case trimming resolution of 0.1%, or equivalently 1fF, with a practically realizable 10fF DAC LSB.

In [3], a frequency-dependent voltage V_C is created by a resistive divider that consists of a fixed resistor and a switched-capacitor resistor. However, the periodic ripple in V_C must be limited by a relatively large stabilizing capacitor. In this work, the need for the latter is obviated by generating V_C in three phases, as shown in Fig. 3.4.2 [6]. During the reset phase, Φ_{RST} , capacitor C_0 is pre-charged to V_{DD} , and during the subsequent discharging phase, Φ_{DCHG} it is discharged through resistor R_0 . At steady-state, the duration of this phase is equal to one period T_{VCO} of the VCO's output frequency, which can be expressed as $T_{VCO} = R_0 C_0 \ln(1 + R_1/R_2) \approx 0.7 R_0 C_0$ and is, ideally, supply-independent. During the third integration phase Φ_{INT} , a G_m -C integrator ($G_m = 5\mu S$, $C_{INT} = 7pF$) integrates the sampled difference between V_R and V_C , which is then used to drive the VCO. To facilitate the generation of the 3-phase control signals, the VCO runs at 40MHz, which is 4× higher than the targeted output frequency (10MHz). This also reduces the required RC constant ($R_0 = 36k\Omega$ and $C_0 = 1pF$) by 4×, and thus the chip area. To improve the FLL's energy efficiency, Φ_{INT} is 2× longer than Φ_{RST} or Φ_{DCHG} . The state of the FLL is thus updated at $F_{VCO}/4$. Setting $R_1 = R_2 = 100k\Omega$ results in an even power split between the RC and resistive-divider branches.

To suppress its 1/f noise and improve the oscillator's long-term stability, the G_m stage is chopped. However, the up-modulated offset will then cause ripples at the control input of the VCO (V_{CTRL}), and thus increase its output jitter. Conventionally, this problem is solved by increasing the chopping frequency or lowering the G_m/C_{INT} ratio [3]. However, the former leads to a larger residual offset and thus worse inaccuracy over PVT, while the latter results in a trade-off between capacitor area and jitter performance. In this design, the size of C_{INT} is drastically reduced by using a compact switched-capacitor notch filter to suppress the ripple [7]. The filter consists of two capacitors C_{MID} (=1.8pF) and C_{HOLD} (=2.7pF) and two switches driven by the sample (ϕ_s) and hold (ϕ_h) signals. As shown in Fig. 3.4.2 (bottom), the voltage across C_{INT} is effectively sampled once every chopping period, resulting in a ripple-free V_{CTRL} at a chopping frequency of $F_{VCO}/8$ (=1.25MHz). Compared to the two-phase filter used in [7], the use of a single-phase filter results in less ripple due to the absence of mismatched charge injection errors, at the expense of 2× more delay. However, the resulting delay is still quite small compared to that of the integrator, and so has a negligible effect on loop stability. The VCO consists of a PMOS current source that drives a 3-stage current-starved ring oscillator, while the G_m stage is a chopped telescopic amplifier with an 80dB DC gain.

The prototype RC frequency reference was fabricated in a standard 0.18µm CMOS technology, as shown in Fig. 3.4.7. To save area, all the resistors and transistors are placed below the Metal-Insulator-Metal (MIM) capacitors, resulting in a compact 100µm×100µm layout. Each frequency reference draws 56.7µA (27.5µA analog and 29.2µA digital) from a 1.5V supply. About 2/3 of the digital power is used to drive the output buffer. Over a 1.5V to 1.8V range, the frequency reference has a supply sensitivity of 2700ppm.

Seven ceramic-packaged chips (112 samples) from one wafer were trimmed and then characterized in a temperature-controlled oven. Since the intra-batch TC spread turned out to be quite small (±8ppm/°C), a fixed TC trim code (corresponding to the simulated TT corner) was used for all samples. As expected, the spread in f_0 is much larger (±1.9%) and was individually trimmed at room temperature (RT, ~25°C).

As shown in Fig. 3.4.3, the frequency reference achieves an inaccuracy of ±0.28% over the automotive temperature range from -45°C to 125°C, resulting in a residual TC of 31.5ppm/°C (box method). However, significant hysteresis (1500ppm worst-case) is observed as the samples are cycled from hot to cold, mainly due to the instability of the polysilicon resistors. Each sample was cycled twice, resulting in a cycle-to-cycle variation of less than ±200ppm, which is much smaller than the observed hysteresis.

Since polysilicon resistors are also known to suffer from drift [8], accelerated aging experiments were conducted by baking the measured samples at 150°C for one week. As shown in Fig. 3.4.4 (top), both the nominal frequency (0.5%) and its TC (10ppm/°C) suffer from drift. However, the former can be trimmed at room temperature with the help of an external reference [9], while the latter is 3× smaller than the original residual TC, and results in much less (0.17%) additional frequency error over life-time. To characterize the effect of packaging stress, seven plastic-packaged chips were also measured. Compared to the ceramic-packaged chips, they required a different TC trim code to achieve similar inaccuracy: ±0.3% from -45°C to 125°C. However, they exhibited somewhat less hysteresis (1200ppm worst-case) as they were cycled from hot to cold.

Figure 3.4.4 (bottom) shows the start-up behaviour of the frequency reference. After setting V_{CTRL} to ground, the output frequency settles within 30µs. Enabling chopping and notch filtering results in a step-wise settling transient, but does not change the settling time. The frequency reference achieves an output period jitter of 41.4ps_{rms} (Fig. 3.4.5, top) and an Allan deviation of 2.3ppm for a 0.6s-stride (Fig. 3.4.5, bottom). Figure 3.4.6 summarizes the performance of the RC-based frequency reference and compares it to the state-of-the-art. Despite the use of a relatively mature 0.18µm technology, it achieves the best on-chip trimmed inaccuracy among compact (<0.02mm²) CMOS frequency references, making it a competitive timing solution for low-cost IoT applications.

References:

- [1] Ç. Gürleyük et al., “A 16 MHz CMOS RC Frequency Reference with ±90 ppm Inaccuracy From -45 °C to 85 °C,” *IEEE JSSC*, vol. 57, no. 8, pp. 2429-2437, Aug. 2022.
- [2] W. Choi et al., “A 0.9-V 28-MHz Highly Digital CMOS Dual-RC Frequency Reference with ±200 ppm Inaccuracy from -40 °C to 85 °C,” *IEEE JSSC*, vol. 57, no. 8, pp. 2418-2428, Aug. 2022.
- [3] A. Khashaba et al., “A 32-MHz, 34µW Temperature-Compensated RC Oscillator Using Pulse Density Modulated Resistors,” *IEEE JSSC*, vol. 57, no. 5, pp. 1470-1479, May 2022.
- [4] J. Wang et al., “A 12.77-MHz 31 ppm/°C On-Chip RC Relaxation Oscillator with Digital Compensation Technique,” *IEEE TCAS-I*, vol. 63, no. 11, pp. 1816-1824, Nov. 2016.
- [5] J. Lee et al., “An Ultra-Low-Noise Swing-Boosted Differential Relaxation Oscillator in 0.18-µm CMOS,” *IEEE JSSC*, vol. 55, no. 9, pp. 2489-2497, Sept. 2020.
- [6] A. Khashaba et al., “A 0.0088mm² Resistor-Based Temperature Sensor Achieving 92fJ-K² FoM in 65nm CMOS,” *ISSCC*, pp. 60-61, Feb. 2020.

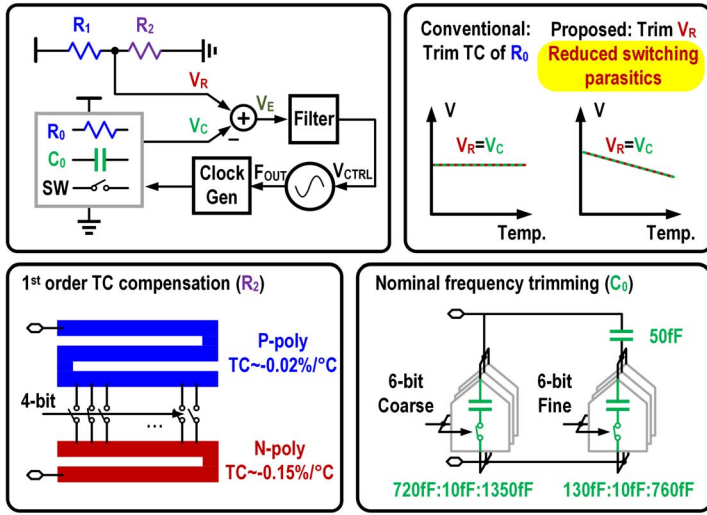


Figure 3.4.1: Block diagram and temperature compensation of an RC frequency reference (top), TC and frequency trimming (bottom).

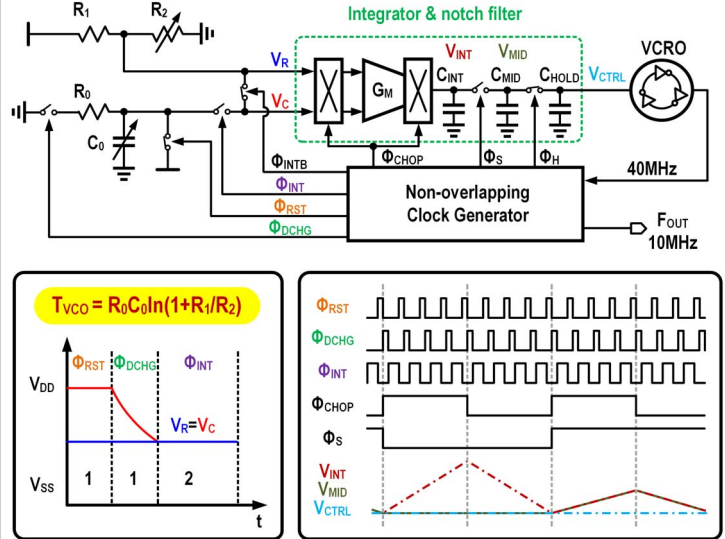


Figure 3.4.2: System block diagram (top) and timing diagram (bottom).

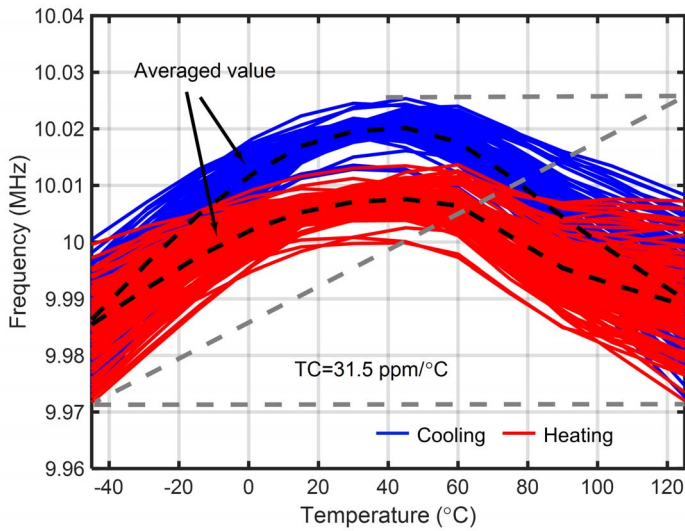


Figure 3.4.3: Temperature sensitivity and hysteresis of the frequency reference (112 samples).

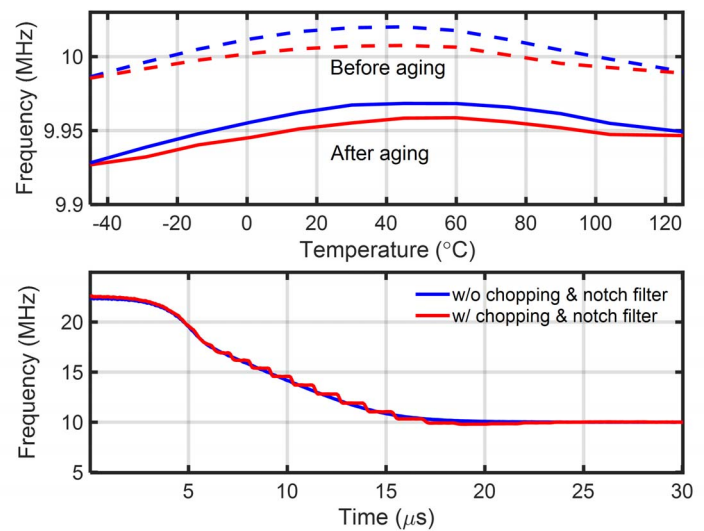


Figure 3.4.4: Averaged frequency of 112 samples before and after aging (top) and Transient response after VCTRL reset (bottom).

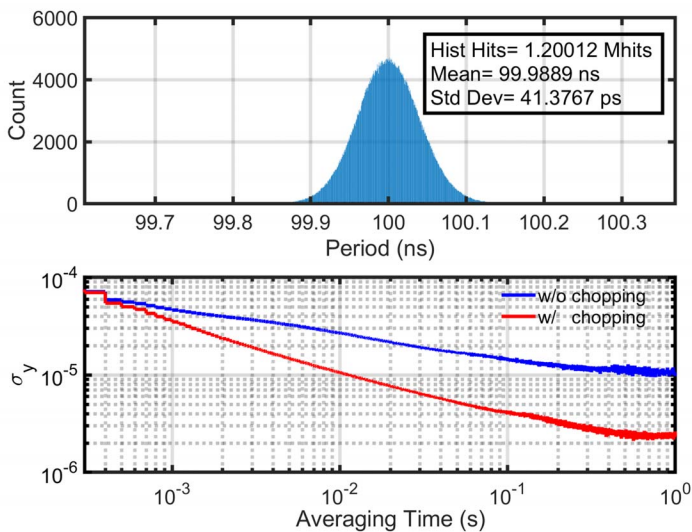


Figure 3.4.5: Measured period jitter (top) and Allan deviation (bottom).

Reference	This work	JSSC 2022 [1]	JSSC 2022 [2]	JSSC 2022 [3]	TCAS-I 2016 [4]	JSSC 2020 [5]
Technology	0.18µm	0.18µm	65nm	65nm	0.18µm	0.18µm
Area [mm²]	0.01	0.3	0.06	0.18	0.012	0.015
Frequency [Hz]	10M	16M	28M	32M	12.77M	10.5M
Power [µW]	85 ^a	220	142	34	56.2	219.8
Energy [pJ/cycle]	8.5 ^a	13.8	5	1.1	4.4	21
Temp. range [°C]	-45~125	-45~85	-40~85	-40~85	-30~120	-45~125
Max. Freq. error [ppm]	±2800	±90	±200	±400	±9000 ^b	-
Temp. coefficient [ppm/°C]	31.5 ^c	1.3 ^c	2.56 ^c	8.4	31	137
Supply range [V]	1.5~1.8	1.6~2	0.85~1.05	1.1~2.3	0.6~1.1	1.4~2.2
Supply sensitivity [ppm/V]	9000	1200	2900	80 ^d	10000	44000
Jitter [ppm]	414	638	196	713	983	104
Allan deviation [ppm]	2.3	0.32	2	2.5	-	2.8
Trimming points	1+batch (1 st order)	2+batch (3 rd order)	2+batch (5 th order)	2	1	0
Number of samples	112	20	16	6	4	15

^a Including driver ^b Estimated from inaccuracy plots ^c Box method ^d LDO used

Figure 3.4.6: Performance summary and comparison with previous RC frequency references.

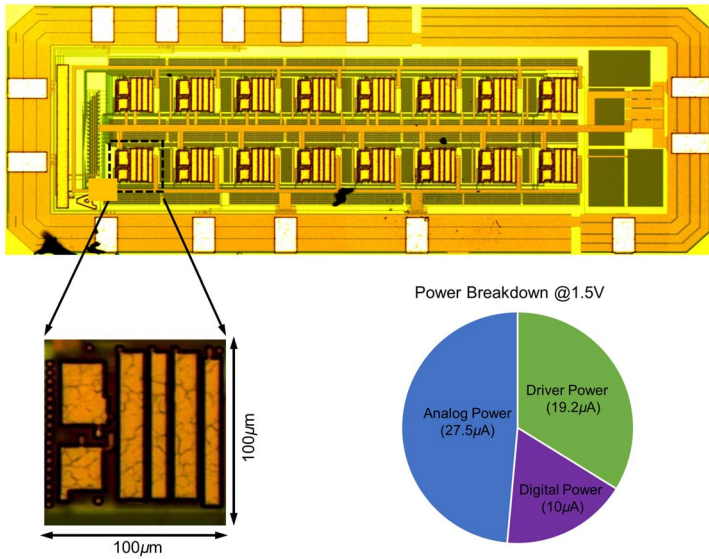


Figure 3.4.7: Die micrograph and its power breakdown.

Additional References:

- [7] P. Park et al., "A Thermistor-Based Temperature Sensor for a Real-Time Clock with ± 2 ppm Frequency Stability," *IEEE JSSC*, vol. 50, no. 7, pp. 1571-1580, July 2015.
- [8] A. Andrei et al., "Reliability Study of AlTi/TiW, Polysilicon and Ohmic Contacts for Piezoresistive Pressure Sensors Applications," *IEEE SENSORS*, pp. 1125-1128, May 2004.
- [9] Microchip Technology Inc., "AN8002 - AVR055: Using a 32kHz XTAL for Run-Time Calibration of the Internal RC," [Online]. Available: <https://ww1.microchip.com/downloads/en/Appnotes/doc8002.pdf>. Accessed Sept. 2022.